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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK3714

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3714 is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3714	Isolated TO-220

FEATURES

• Super low on-state resistance

 $R_{DS(on)1} = 13 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = 10 \text{ V, ID} = 25 \text{ A)}$

 $R_{DS(on)2} = 22 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 4.0 \text{ V, ID} = 25 \text{ A)}$

- Low Ciss: Ciss = 3200 pF TYP.
- Built-in gate protection diode

(Isolated TO-220)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	60	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±50	Α
Drain Current (pulse) Note1	D(pulse)	±160	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	35	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current Note2	las	31	Α
Single Avalanche Energy Note2	Eas	96	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting Tch = 25°C, VDD = 30 V, RG = 25 Ω , VGS = 20 \rightarrow 0 V

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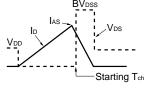


ELECTRICAL CHARACTERISTICS (TA = 25°C)

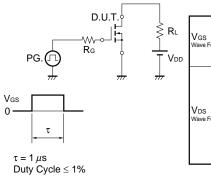
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 60 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 25 A	17	34		S
Drain to Source On-state Resistance Note	RDS(on)1	Vgs = 10 V, ID = 25 A		11	13	mΩ
	RDS(on)2	Vgs = 4.0 V, ID = 25 A		16	22	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		3200		pF
Output Capacitance	Coss	Vgs = 0 V		520		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		260		pF
Turn-on Delay Time	td(on)	V _{DD} = 30 V, I _D = 25 A		15		ns
Rise Time	tr	Vgs = 10 V		10		ns
Turn-off Delay Time	td(off)	$R_G = 0 \Omega$		58		ns
Fall Time	tf			7		ns
Total Gate Charge	Q _G	V _{DD} = 48 V		60		nC
Gate to Source Charge	Qgs	Vgs = 10 V		10		nC
Gate to Drain Charge	Q _{GD}	lo = 50 A		16		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	IF = 50 A, VGS = 0 V		0.94	1.5	V
Reverse Recovery Time	trr	IF = 50 A, VGS = 0 V		46		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		80		nC

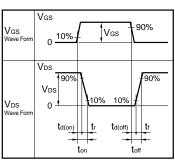
★ Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME



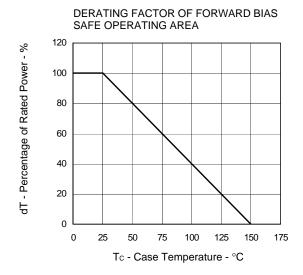


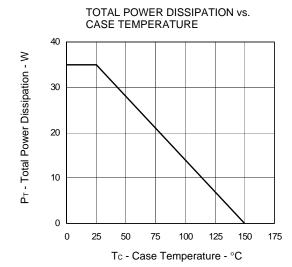
TEST CIRCUIT 3 GATE CHARGE

$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \text{ mA} \\ \hline \end{array}$$

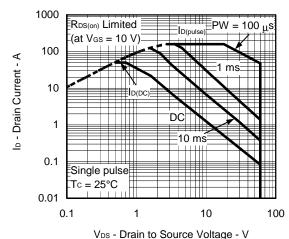
$$\begin{array}{c|c} PG. & \begin{array}{c} \\ \\ \end{array} & \begin{array}{c} \\ \end{array} & \begin{array}{c} \\ \\ \end{array} & \begin{array}{c$$

TYPICAL CHARACTERISTICS (TA = 25°C)



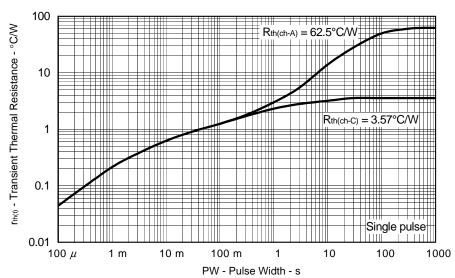


★ FORWARD BIAS SAFE OPERATING AREA



bource voltage - v

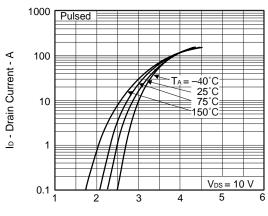
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



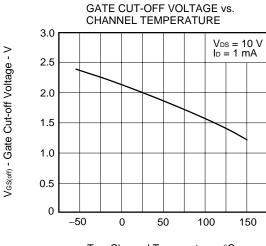
Data Sheet D16537EJ2V0DS 3

DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE 100 80 lo - Drain Current - A 60 Vgs = 10 V 40 4.0 V 20 Pulsed 0 0.2 0.4 0.6 V_{DS} - Drain to Source Voltage - V

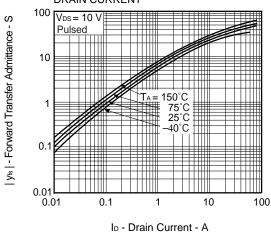
FORWARD TRANSFER CHARACTERISTICS



V_{GS} - Gate to Source Voltage - V

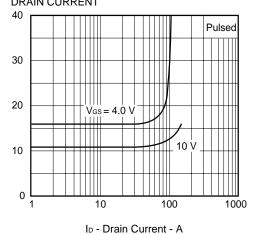


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

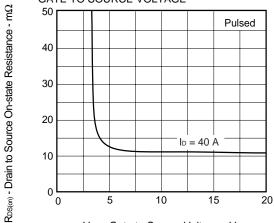


Tch - Channel Temperature - °C

DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



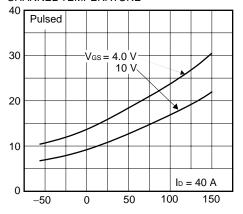
V_{GS} - Gate to Source Voltage - V

 $\mathsf{R}_{\mathsf{DS}(m)}$ - Drain to Source On-state Resistance - $m\Omega$

 $\mathsf{R}_{\mathsf{DS}(m)}$ - Drain to Source On-state Resistance - $m\Omega$

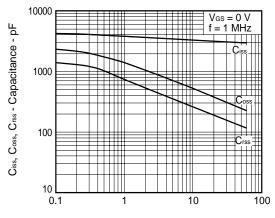
IF - Diode Forward Current - A

DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



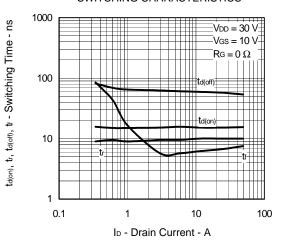
Tch - Channel Temperature - °C

CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

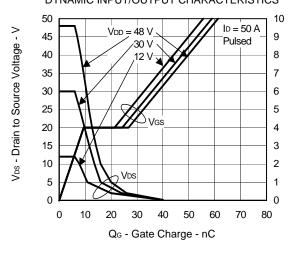


V_{DS} - Drain to Source Voltage - V

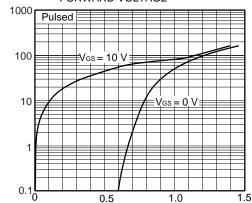
SWITCHING CHARACTERISTICS



DYNAMIC INPUT/OUTPUT CHARACTERISTICS

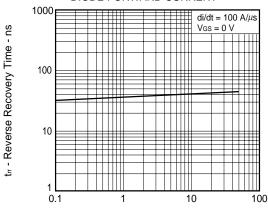


SOURCE TO DRAIN DIODE FORWARD VOLTAGE



V_{F(S-D)} - Source to Drain Voltage - V

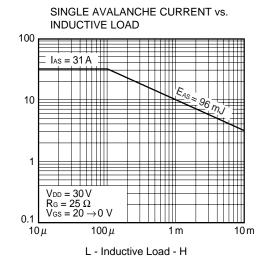
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



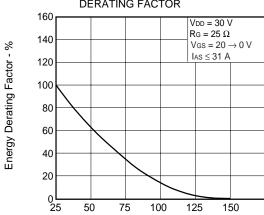
IF - Diode Forward Current - A

Ves - Gate to Source Voltage - V



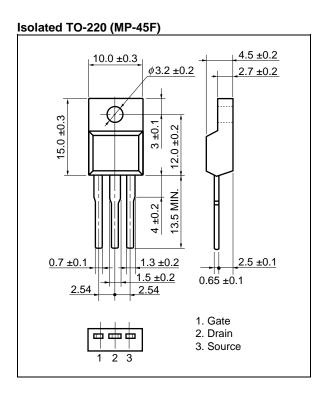


SINGLE AVALANCHE ENERGY DERATING FACTOR

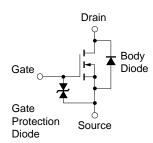


Starting T_{ch} - Starting Channel Temperature - $^{\circ}C$

PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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